



20V P-Channel Enhancement Mode MOSFET - ESD Protected

Voltage

-20 V

Current

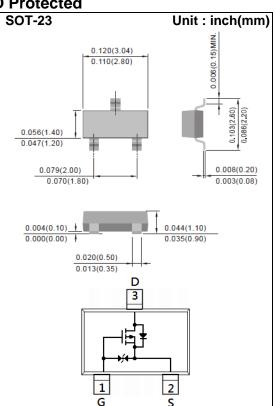
-4.3A

Features

- RDS(ON), VGS@-4.5V, ID@-4.3A< $50m\Omega$
- RDS(ON), VGS@-2.5V, ID@-4.0A<58mΩ
- RDS(ON) , VGS@-1.8V, ID@-2.4A<73mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A5AE



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	-4.3	Α
Pulsed Drain Current		I _{DM}	-17.2	Α
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-0.4	-0.55	-1.0	V
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =-4.5V, I_{D} =-4.3A	-	42	50	mΩ
		V _{GS} =-2.5V, I _D =-4.0A	-	49	58	
		V _{GS} =-1.8V, I _D =-2.4A	-	59	73	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\underline{+}8V, V_{DS}=0V$	-	<u>+</u> 6	<u>+</u> 10	uA
Dynamic (Note 5)						
Total Gate Charge	Q_g	V _{DS} =-10V, I _D =-4.3A, V _{GS} =-4.5V ^(Note 1,2)	-	24	-	nC
Gate-Source Charge	Q_gs		-	1.5	-	
Gate-Drain Charge	Q_{gd}		-	2.5	-	
Input Capacitance	Ciss	V _{DS} =-10V, V _{GS} =0V,	-	907	-	pF
Output Capacitance	Coss		-	90	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	70	-	
Turn-On Delay Time	td _(on)	101/1	-	45	-	
Turn-On Rise Time	tr	V_{DD} =-10V, I_{D} =-4.3A, V_{GS} =-4.5V, R_{G} =6 Ω (Note 1.2)	-	79	-	ns
Turn-Off Delay Time	td _(off)		-	193	-	
Turn-Off Fall Time	tf	K _G =012	-	826	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		_	-	-1.5	А
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V	-	0.76	-1.2	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

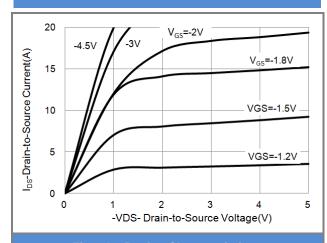


Fig.1 On-Region Characteristics

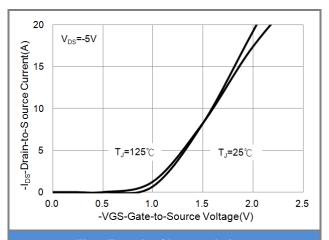


Fig.2 Transfer Characteristics

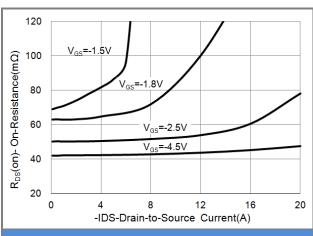


Fig.3 On-Resistance vs. Drain Current

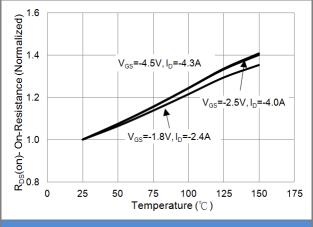
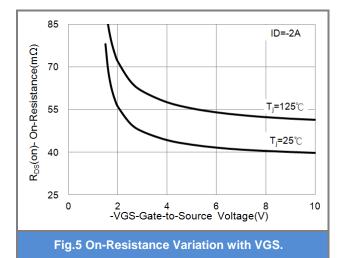


Fig.4 On-Resistance vs. Junction temperature



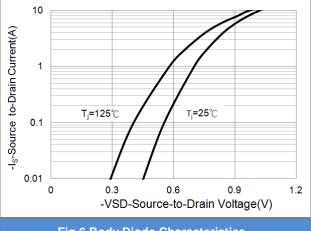


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

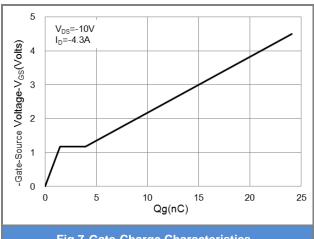
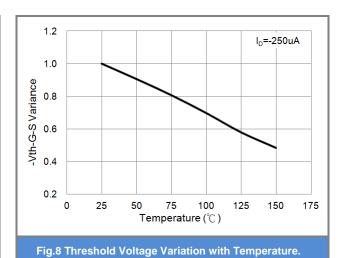


Fig.7 Gate-Charge Characteristics



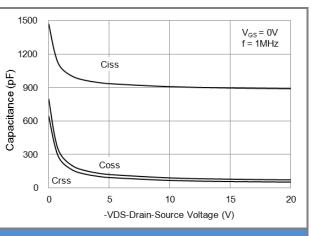


Fig.9 Capacitance vs. Drain-Source Voltage.

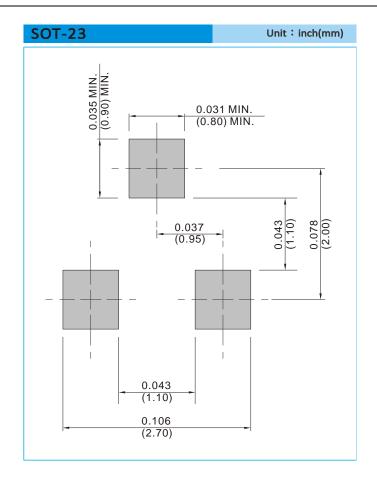




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3415AE_R1_00001	SOT-23	3K pcs / 7" reel	A5AE	Halogen free
PJA3415AE_R2_00001	SOT-23	12K pcs / 13" reel	A5AE	Halogen free

MOUNTING PAD LAYOUT







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